

**DECT Power Amplifier**  
**1880 - 1930 MHz**
**MAAPSS0071**  
**V2**
**Features**

- Ideal for DECT Applications
- Saturated Output Power: +26 dBm Typical
- Power Gain: 26 dB Typical
- Low Current: 400 mA at  $P_{SAT}$
- Ramp Power Control
- Micro-Amp Shutdown
- Operates from 1.5 V to 4.0 V
- Lead-Free 3 mm 12-Lead PQFN Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- RoHS\* Compliant 260°C Reflow Compatible

**Description**

The MAAPSS0071 is a three stage power amplifier designed for Cordless Telephone applications. This power amplifier is mounted in a standard outline, lead-free 3 mm 12-lead PQFN plastic package. The MAAPSS0071 features an integrated power enable control pin.

**Ordering Information**

Part Number	Package
MAAPSS0071	Bulk Packaging
MAAPSS0071TR-3000	3000 piece reel
MAAPSS0071SMB	Sample Test Board (Includes 5 Samples)

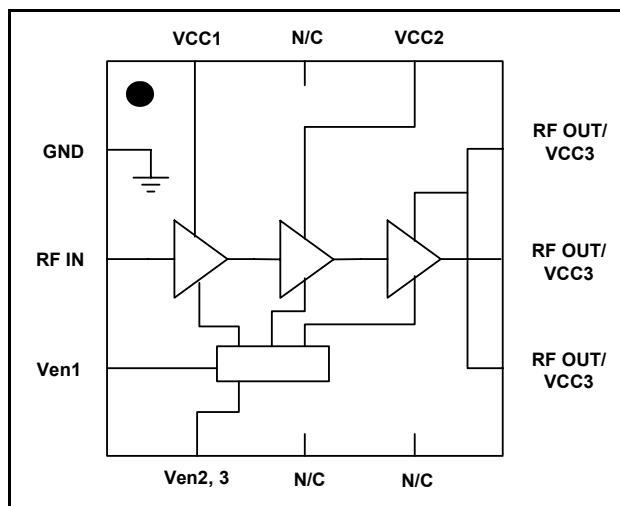
Note: Reference Application Note M513 for reel size information.

**Absolute Maximum Ratings**<sup>1,2</sup>

Parameter	Absolute Maximum
Input Power	+ 5 dBm
Operating Supply Voltage	+4.0 Volts
Operating Control Voltage	+3.0 Volts
Operating Temperature	-20°C to +85°C
Channel Temperature	+150°C
Storage Temperature	-40°C to +150°C

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. M/A-COM does not recommend sustained operation near these survivability limits.

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

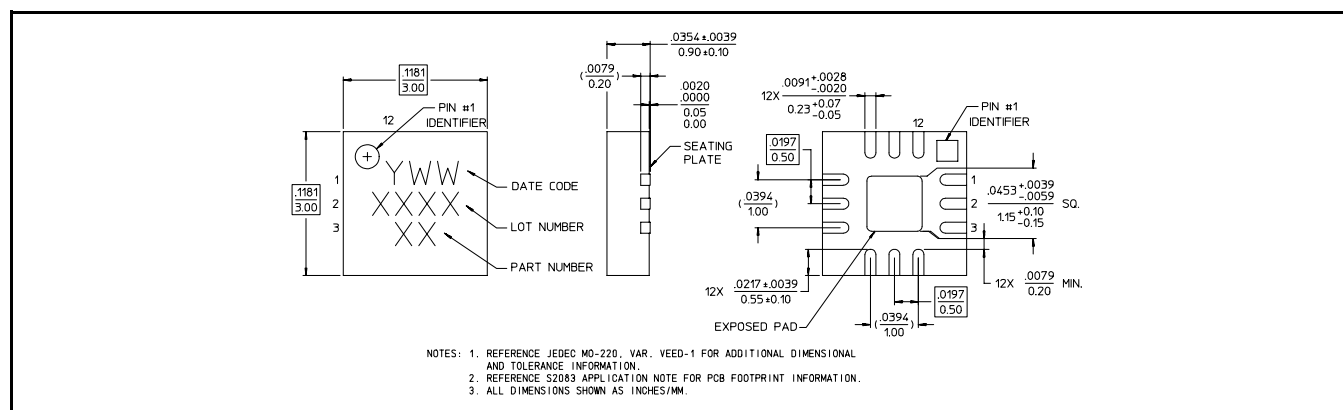
**Functional Schematic**

**Pin Configuration**

PIN No.	PIN Name	Description
1	GND	Ground
2	RF <sub>IN</sub>	RF Input
3	V <sub>EN1</sub>	Power Enable
4	V <sub>EN2,3</sub>	Power Enable
5	N/C	No Connection
6	N/C	No Connection
7	RF <sub>OUT</sub> / V <sub>CC3</sub>	RF Output, 3rd Stage Supply
8	RF <sub>OUT</sub> / V <sub>CC3</sub>	RF Output, 3rd Stage Supply
9	RF <sub>OUT</sub> / V <sub>CC3</sub>	RF Output, 3rd Stage Supply
10	V <sub>CC2</sub>	2nd Stage Supply
11	N/C	No Connection
12	V <sub>CC1</sub>	1st Stage Supply
Pad <sup>3</sup>	GND	RF & DC Ground

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.

**DECT Power Amplifier**  
**1880 - 1930 MHz**
**MAAPSS0071**  
**V2**
**Electrical Specifications:**
**Frequency = 1905 MHz,  $P_{IN}$  = -2 to 2 dBm,  $V_{CC}$  = 2.4 V,  $V_{EN}$  = 2.5 V,  $T_A$  = 25 °C,  $Z_0$  = 50 $\Omega$** 

Parameter	Test Conditions	Units	Min.	Typ.	Max
Input Return Loss	—	dB	—	15	—
Output Power	—	dBm	24	26	27
Power Flatness	$2.0 < V_{CC} < 3.0$ V	dB	—	3	—
PAE	—	%	—	45	—
Current	—	mA	—	400	500
Current, Off	$V_{EN} = 0$ V	$\mu$ A	—	3	10
Pdiss	$P_{OUT} = 26.0$ dBm	W	—	0.5	—
Control Pins	$V_{EN}$ , Low $V_{EN}$ , High Current	V V mA	0 2.0 —	— — 2.0	0.5 2.5 4.0
Harmonics	2f 3f	dBc dBc	— —	-35 -40	— —
Forward Isolation	$V_{EN} = 0$ V	dB	—	39	—
Duty Cycle	—	%	—	—	100
Turn on/off time	Ton: RF burst to NTP-1 Toff: NTP-1 to off	$\mu$ S $\mu$ S	— —	3 2	— —
Stability	$+1.5V < V_{CC} < +3.5$ V, $P_{IN} = -2$ to 2 dBm, VSWR < 6:1 $-20^{\circ}\text{C} < T_C < +70^{\circ}\text{C}$ , RBW = 3 MHz max hold		All spurs < -60 dBc		

**Lead-Free 3 mm 12-Lead PQFN<sup>†</sup>**

<sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.

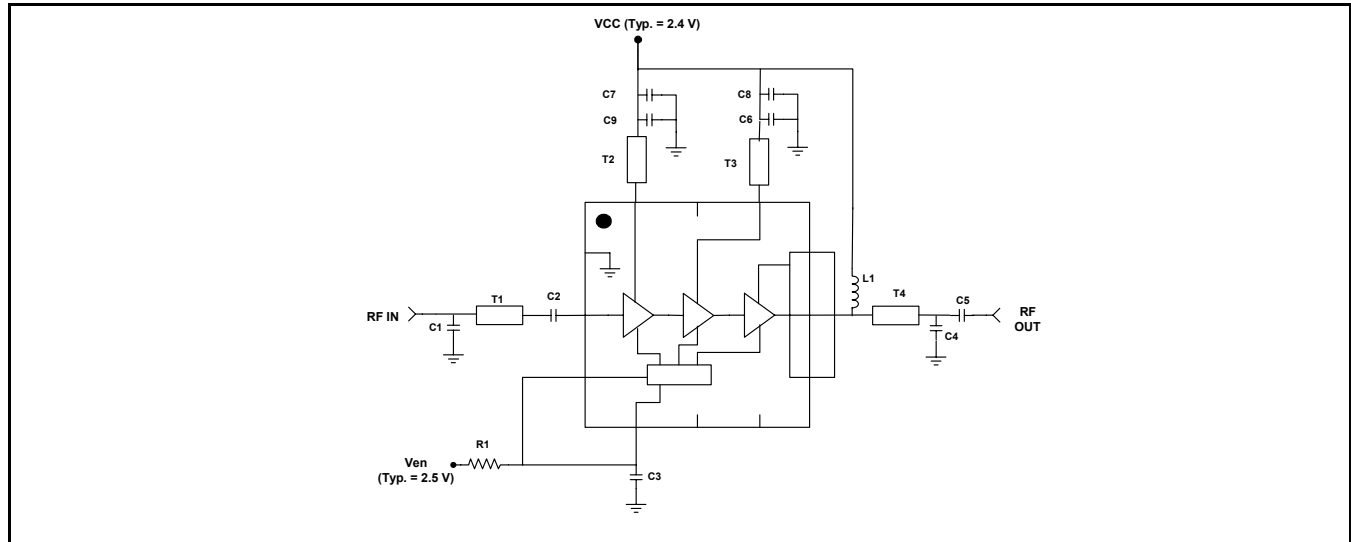
**Operating the MAAPSS0071**

The MAAPSS0071 can be damaged by electrostatic discharge (ESD). Use proper ESD control techniques when handling this device. To operate the MAAPSS0071, turn on the  $V_{CC}$  before  $V_{EN}$  for power on and turn off  $V_{CC}$  after  $V_{EN}$  for shutdown.

**DECT Power Amplifier  
1880 - 1930 MHz**

**MAAPSS0071  
V2**

**Evaluation Board Schematic**



**MAAPSS0071 External Parts List**

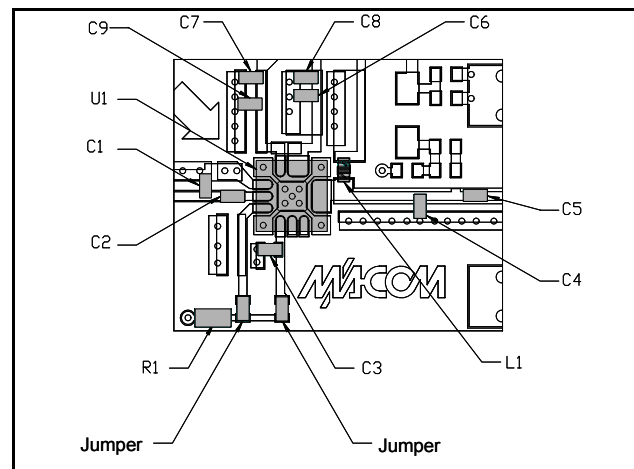
Designator	Value	Footprint	Manufacturer	Part ID
C1	1 pF	0402	Murata	GRM1555C1H1R0CZ01B
C2, C4	3 pF	0402	Murata	GRM1555C1H3R0CZ01B
C3	22 nF	0402	Murata	GRM155R71C223KA01B
C5, C6	47 pF	0402	Murata	GRM1555C1H470JZ01B
C7, C8	100 nF	0402	Murata	GRM155F51C104ZA01B
C9	4 pF	0402	Murata	GRM155C1H4R0CZ01B
R1	475 Ohm	0402	Panasonic	ERJ-3EKF4750V
L1	10 nH	0402	Coilcraft	0402CS-10NXJB

**Transmission Line Dimensions, 0.20 mm thick FR4**

Designator	Length (mm) <sup>4</sup>	Width (mm)
T1 <sup>5</sup>	2.16	0.37
T2	2.54	0.37
T3	3.05	0.37
T4	3.94	0.37

4. From package edge to center of component.

5. T1 is measured from package edge (not C2) to the center of C1.

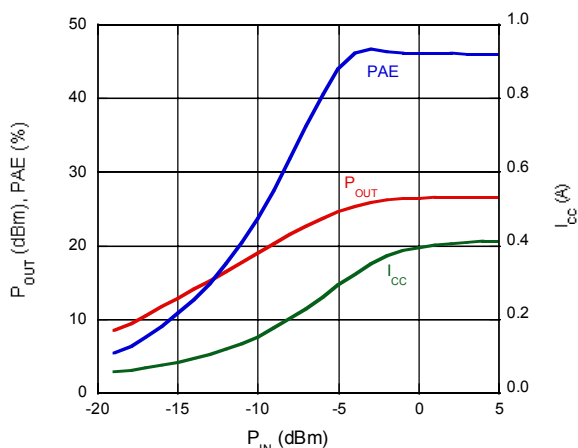


**DECT Power Amplifier  
1880 - 1930 MHz**

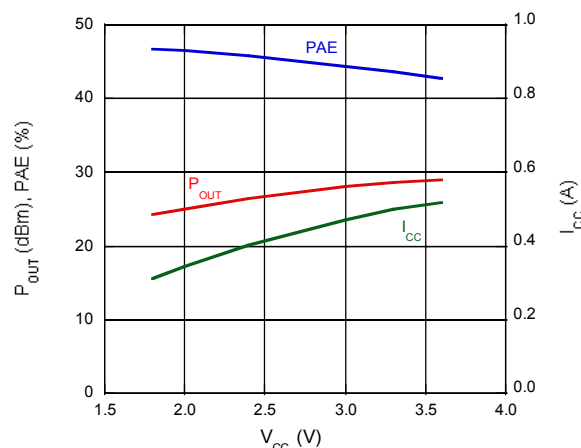
**MAAPSS0071  
V2**

**Typical Characteristics (Using the supplied sample board BOM)**

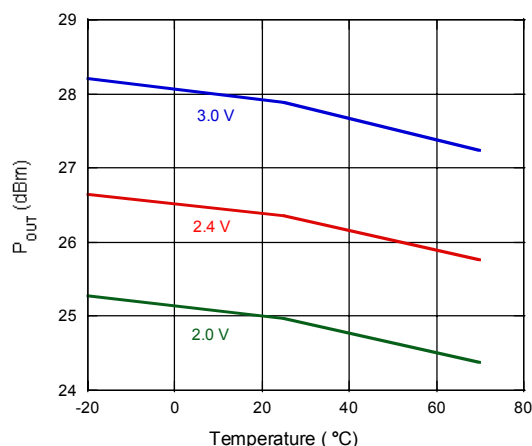
**$P_{OUT}$ , PAE,  $I_{CC}$  vs.  $P_{IN}$  @ 2.4 V, 1900 MHz**



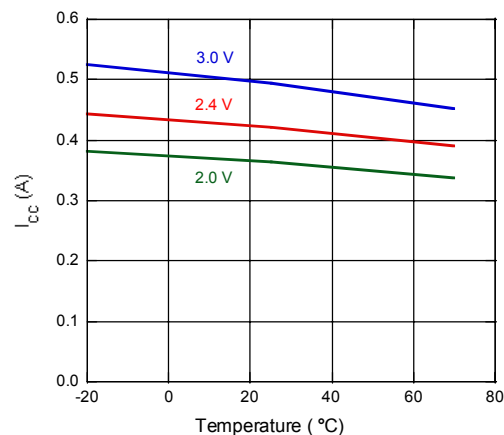
**$P_{OUT}$ , PAE,  $I_{CC}$  vs.  $V_{CC}$  @ 1900 MHz,  $P_{IN} = 0$  dBm**



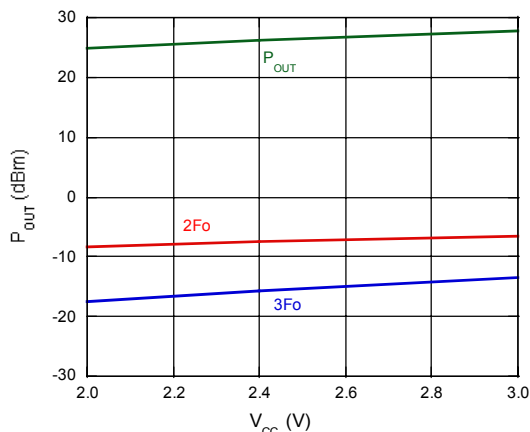
**$P_{OUT}$  vs. Temperature @ 1900 MHz,  $P_{IN} = 0$  dBm**



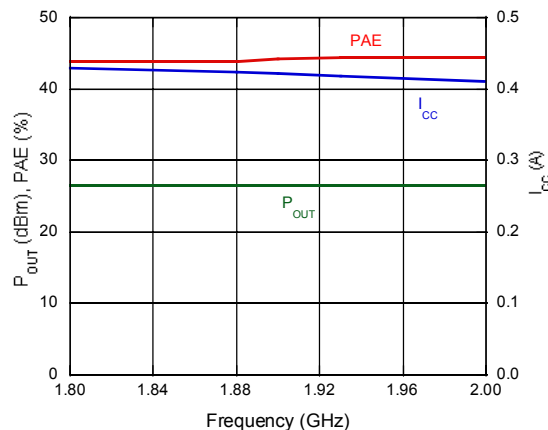
**$I_{CC}$  vs. Temperature @ 1900 MHz,  $P_{IN} = 0$  dBm**



**$P_{OUT}$  vs.  $V_{CC}$  @ 1900 MHz,  $P_{IN} = 0$  dBm**



**$P_{OUT}$ , PAE,  $I_{CC}$  vs. Frequency @  $V_{CC} = 2.4$  V,  $P_{IN} = 0$  dBm**

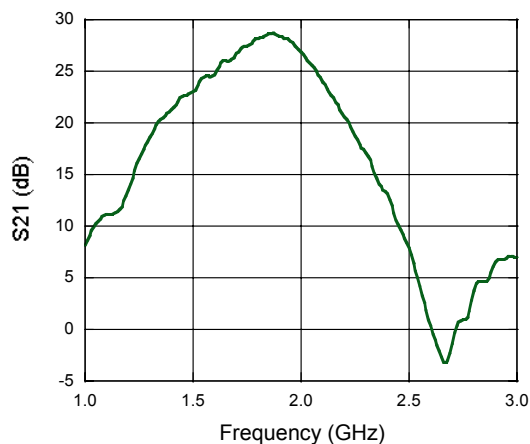


**DECT Power Amplifier  
1880 - 1930 MHz**

**MAAPSS0071  
V2**

**Typical Characteristics (Using the supplied sample board BOM)**

***S21 vs. Frequency @  $V_{CC} = 2.4\text{ V}$ ,  $V_{EN} = 2.5\text{ V}$***



***S22, S11 vs. Frequency @  $V_{CC} = 2.4\text{ V}$ ,  $V_{EN} = 2.5\text{ V}$***

